

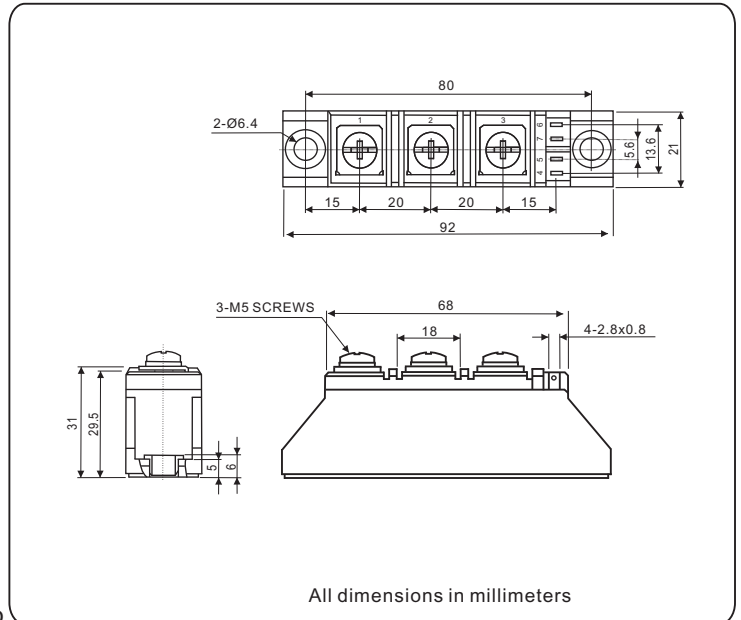
Thyristor/Diode and Thyristor/Thyristor, 90A (ADD-A-PAK Power Modules)



ADD-A-PAK

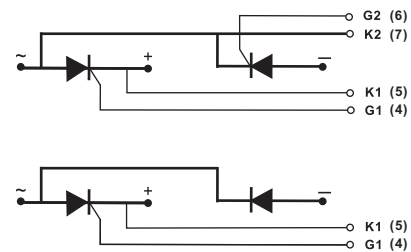
FEATURES

- High voltage
- Electrically isolated by DBC ceramic (Al_2O_3)
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- High surge capability
- Planar SCR chips
- Modules uses high voltage power thyristors/diodes in two basic configurations
- Simple mounting
- UL approved file E320098 
- Compliant to RoHS
- Designed and qualified for multiple level



APPLICATIONS

- DC motor control and drives
- Battery charges
- Welders
- Power converters
- Lighting control
- Heat and temperature control



NKT

NKH

PRODUCT SUMMARY

$I_{T(AV)}$	90 A
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MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUE	UNITS
$I_{T(AV)}$	85 °C	90	A
$I_{T(RMS)}$	85 °C	141	A
I_{TSM}/I_{FSM}	50 Hz	2000	A
	60 Hz	2100	
I^2t	50 Hz	20	kA^2s
	60 Hz	18.3	
$I^2\sqrt{t}$		200	$\text{kA}^2\sqrt{\text{s}}$
$V_{\text{DRM}} / V_{\text{RRM}}$	Range	400 to 1600	V
T_J	Range	-40 to 125	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM}/V_{DRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}/V_{DSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM}/I_{DRM} AT 125 °C mA
NKT90..A NKH90..A	04	400	500	10
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS			VALUE	UNITS		
Maximum average on-state current at case temperature	I _{T(AV)}	180° conduction, half sine wave ,50Hz			90	A		
					85	°C		
Maximum RMS on-state current	I _{T(RMS)}	180° conduction, half sine wave ,50Hz ,T _C = 85°C			141	A		
Maximum peak, one-cycle, on-state non-repetitive surge current	I _{TSM}	t = 10 ms	No voltage reappplied	Sine half wave, initial T _J = T _J maximum	2000			
		t = 8.3 ms			2100			
Maximum I ² t for fusing	I ² t	t = 10 ms			100%V _{RRM} reappplied		20	kA ² s
		t = 8.3 ms					18.3	
		t = 10 ms		14				
		t = 8.3 ms		12.8				
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reappplied			200	kA ² √s		
Maximum on-state voltage drop	V _{TM}	I _{TM} = 270A , T _J = 25 °C, 180° conduction			1.6	V		
Maximum forward voltage drop	V _{FM}	I _{FM} = 270A , T _J = 25 °C, 180° conduction			1.3			
Maximum holding current	I _H	Anode supply = 6 V,resistive load T _J = 25 °C			150	mA		
Maximum latching current	I _L	Anode supply = 6 V resistive load, T _J = 25 °C			400			

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse and off-state leakage current	I_{RRM} I_{DRM}	$T_J = 125^\circ\text{C}$	10	mA
RMS isolation Voltage	V_{ISO}	50 Hz, circuit to base, all terminals shorted	2500 (1min) 3000 (1s)	V
Critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, exponential to 67 % rated V_{DRM}	1000	V/μs

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P _{GM}	t _p ≤ 5 ms, T _J = T _J maximum		10	W
Maximum average gate power	P _{G(AV)}	f = 50 Hz, T _J = T _J maximum		3	
Maximum peak gate current	I _{GM}	t _p ≤ 5 ms, T _J = T _J maximum		3	A
Maximum peak negative gate voltage	- V _{GM}			10	V
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C	Anode supply = 6 V, resistive load; R _a = 1 Ω	0.7~1.6	
Maximum required DC gate current to trigger	I _{GT}			20~100	mA
Maximum gate voltage that will not trigger	V _{GD}	T _J = T _J maximum, 66.7% V _{DRM} applied		0.25	V
Maximum gate current that will not trigger	I _{GD}			10	mA
Maximum rate of rise of turned-on current	dl/dt	T _J = 25°C ,I _{GM} = 1.5A ,t _r ≤ 0.5 μs		150	A/μs

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	T _J		- 40 to 125	°C
Maximum storage temperature range	T _{Stg}		- 40 to 150	
Maximum thermal resistance, junction to case per junction	R _{thJC}	DC operation	0.28	°C/W
Maximum thermal resistance, case to heatsink per module	R _{thCS}	Mounting surface, smooth , flat and greased	0.077	
Mounting torque ± 10 %	AAP to heatsink, M6 busbar to AAP, M5	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.	4	N.m
Approximate weight			120	g
			4.23	oz.
Case style			ADD-A-PAK	

ORDERING INFORMATION TABLE

Device code

NKT	90	/	16	A
①	②		③	④

- ① - Module type: NKT for (Thyristor + Thyristor) module
NKH for (Thyristor + Diode) module
- ② - Current rating: $I_{T(AV)}$
- ③ - Voltage code $\times 100 = V_{RRM}$
- ④ - Assembly type, "A" for soldering type

Fig.1 Peak On-state voltage vs. peak On-state current

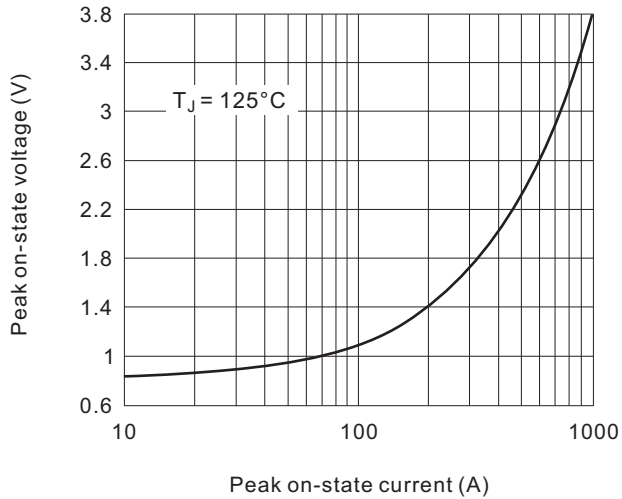


Fig.2 Max. thermal impedance (junction to case) vs. time

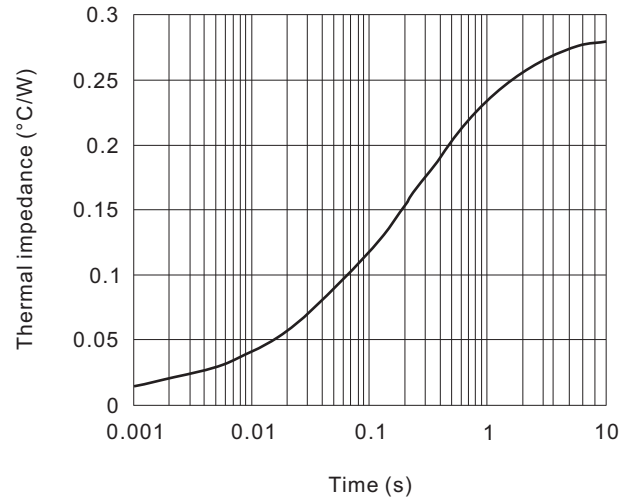


Fig.3 Power dissipation vs. average on-state current

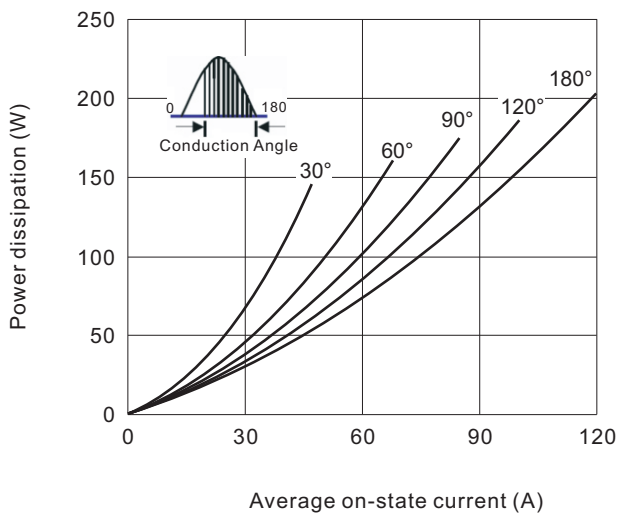


Fig.4 Case temperature vs. average on-state current

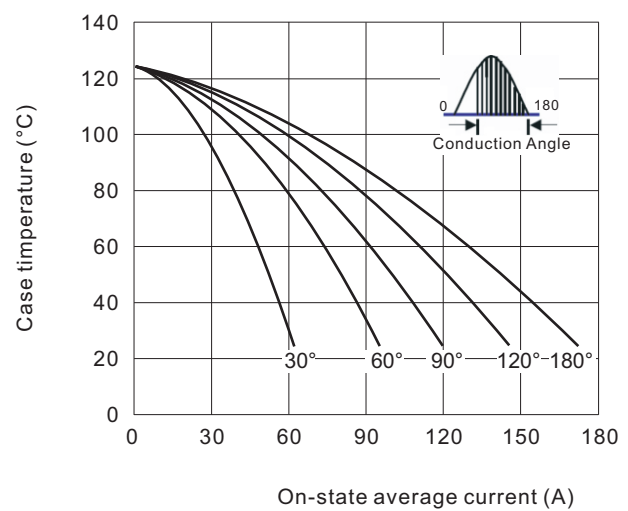


Fig.5 Surge on-state current vs. cycles

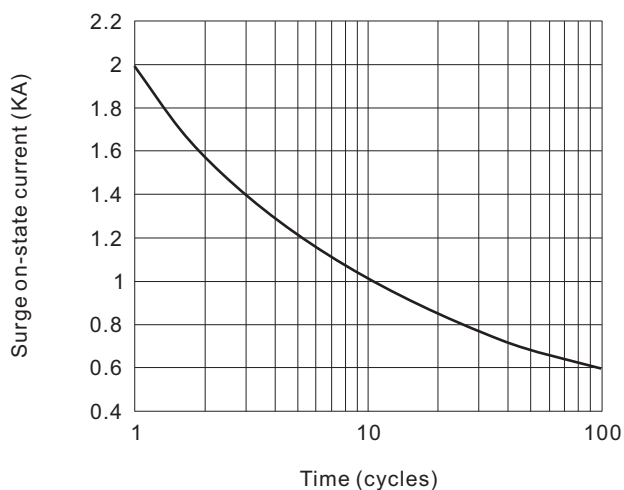


Fig.6 Gate characteristics

